

## NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

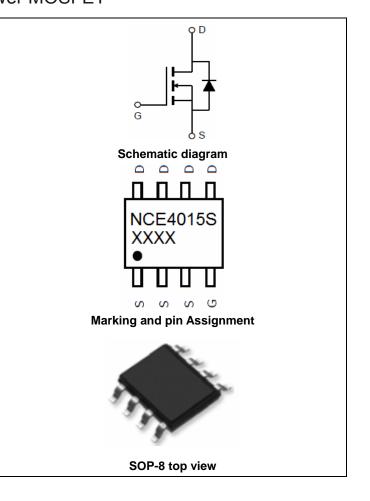
The NCE4015S uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

- V<sub>DS</sub> =40V,I<sub>D</sub> =15A
  - $R_{DS(ON)}$  <10m $\Omega$  @  $V_{GS}$ =10V (Typ. 6.1 m $\Omega$ )
  - $R_{DS(ON)}$  <15m $\Omega$  @  $V_{GS}$ =4.5V (Typ. 11.4 m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply



#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE4015S	NCE4015S	SOP-8	Ø330mm	12mm	2500 units

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	15	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	10.6	Α
Pulsed Drain Current	I <sub>DM</sub>	70	Α
Maximum Power Dissipation	P <sub>D</sub>	3.1	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>θJA</sub>	40	°C/W
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# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u>.                                      </u>					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA 40		45	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V -		-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	<u>.                                      </u>					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.2	1.8	2.5	V
Drain-Source On-State Resistance	-	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	6.1	10	mΩ
Dialii-Source Oii-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =8A	-	11.4	15	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =10A		80	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C <sub>lss</sub>	\/ 00\/\/ 0\/	-	3090	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =20V, $V_{GS}$ =0V, F=1.0MHz	-	328	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0lvln2	-	273	-	PF
Switching Characteristics (Note 4)	<u>.                                      </u>					
Turn-on Delay Time	t <sub>d(on)</sub>		-	7	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =20V, $R_L$ =2 $\Omega$	-	20	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$	-	34	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	19	-	nS
Total Gate Charge	Qg	V 00V/1 40A	-	60		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=20V,I_{D}=10A,$	-	8.1		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	16.9		nC
Drain-Source Diode Characteristics	<u> </u>		1			·
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =10A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	15	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 10A	-	31	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	33	-	nC

#### Notes:

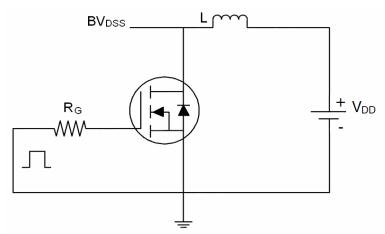
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

**Pb Free Product** 

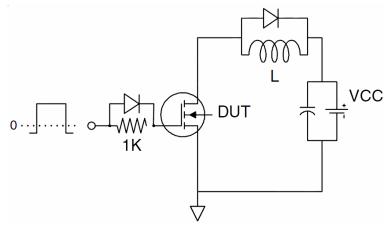
# NCE4015S

#### **Test circuit**

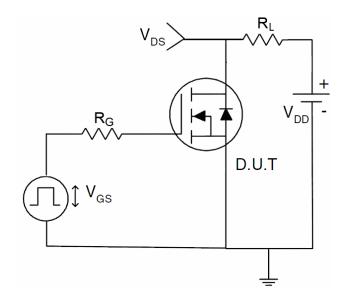
# 1) E<sub>AS</sub> Test Circuit



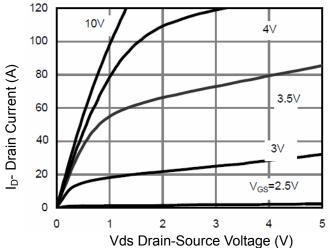
# 2) Gate Charge Test Circuit



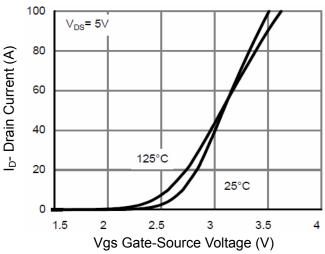
# 3) Switch Time Test Circuit



### Typical Electrical and Thermal Characteristics (Curves)



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

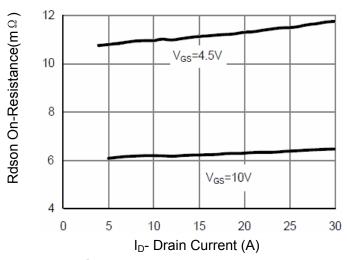


Figure 3 Rdson- Drain Current

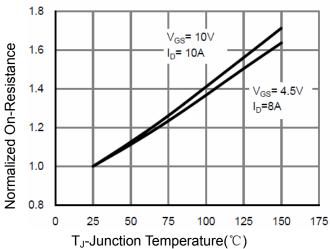


Figure 4 Rdson-JunctionTemperature

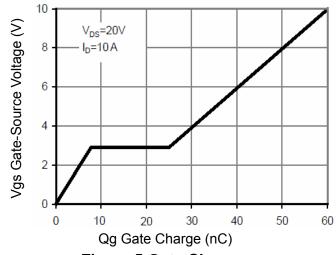


Figure 5 Gate Charge

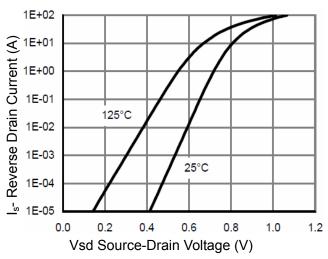
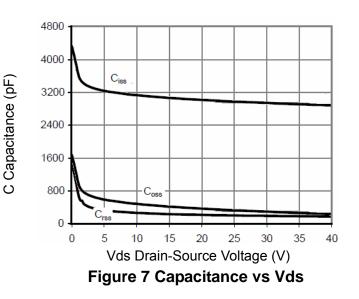


Figure 6 Source- Drain Diode Forward



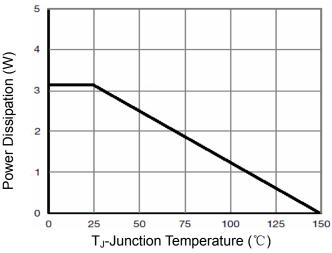
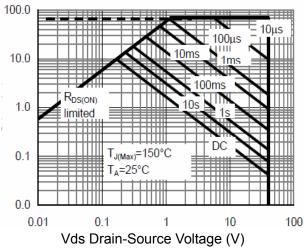
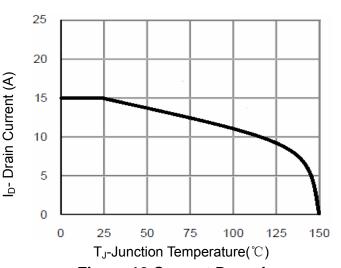


Figure 9 Power De-rating





**Figure 8 Safe Operation Area** 

Figure 10 Current De-rating

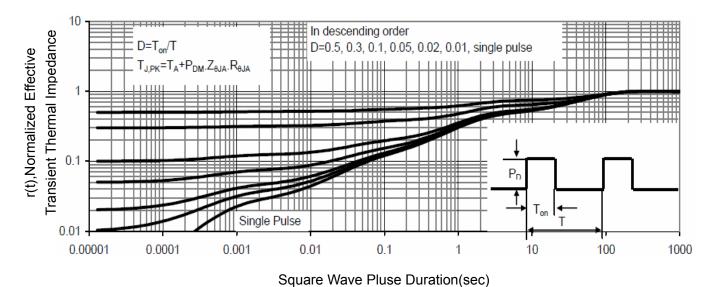
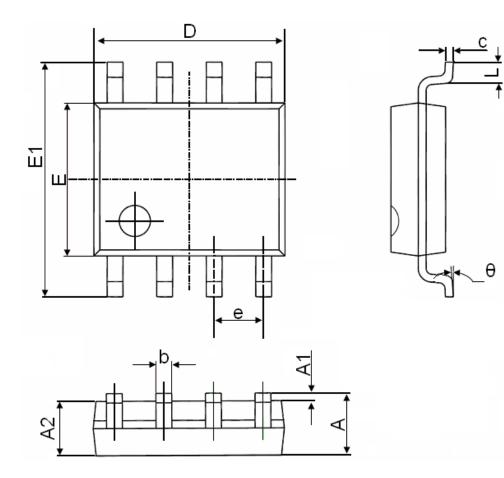


Figure 11 Normalized Maximum Transient Thermal Impedance



# **SOP-8 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	1.270(BSC)		(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



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NCE4015S

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